
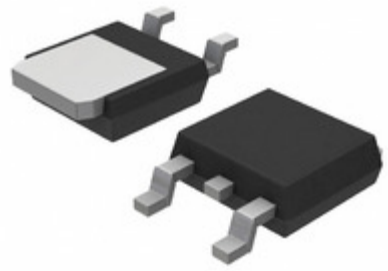
	<h2 style="color: red;">NTD20N03L27G</h2>
	<p>Hersteller-Teilenummer: NTD20N03L27G</p> <hr/> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 30V 20A DPAK</p> <hr/> <p>Datenblätter:  NTD20N03L27G.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 17548 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NTD20N03L27G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 30V 20A DPAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	17548 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	1.75W (Ta), 74W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	20A (Ta)
Rds On (Max) @ Id, Vgs	27 mOhm @ 10A, 5V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	18.9nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1260pF @ 25V
Verpackung	Tube


























NTD20N03L27G ist neu im Original. Suche NTD20N03L27G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD20N03L27G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD20N03L27G: Info@Y-IC.com

Sie können auch interessiert sein:

 NTD20N03L ON NTD20N03L ON	 NTD20N03L27T4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 20A DPAK	 NTD20N03L27-1 ON NTD20N03L27-1 ON	 NTD20N03LT4G O O TO252
 NTD20N03L27T ON NTD20N03L27T ON	 NTD20N03LG ON NTD20N03LG ON	 NTD20N03L27-1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 20A IPAk	 NTD20N03L27 AMI Semiconductor / ON Semiconductor MOSFET N-CH 30V 20A DPAK

heiße Teile

Mehr

 NTD14N03RT4G	 NTD14N03RTCG	 NTD14N03T4G	 NTD15N06	 NTD15N06L
 NTD15N06LG	 NTD15N06LT4	 NTD15N06LT4G	 NTD15N06T4	 NTD15N06T4G
 NTD15N06VLT4	 NTD15N07	 NTD15N10	 NTD18N06-001	 NTD18N06-1G
 NTD18N06G	 NTD18N06L	 NTD18N06L-1G	 NTD18N06LG	 NTD18N06LT4G
 NTD18N06T4G	 NTD20N03	 NTD20N03G	 NTD20N03HL	 NTD20N03L27
 NTD20N03L27T	 NTD20N03L27T4	 NTD20N03L27T4G	 NTD20N03RT4G	 NTD20N06
 NTD20N06-001	 NTD20N06-1G	 NTD20N06HD	 NTD20N06HDLT4G	 NTD20N06HL
 NTD20N06L	 NTD20N06L-001	 NTD20N06L-1G	 NTD20N06LG	 NTD20N06LT4
 NTD20N06LT4G	 NTD20N06T4G	 NTD20N06V	 NTD20P03	 NTD20P03HDLT4G
 NTD20P06HCT4G	 NTD20P06HD	 NTD20P06HDLT4	 NTD20P06HL	 NTD20P06L

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